TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7MH161FK,TC7MH163FK

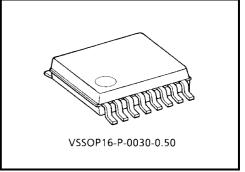
Synchronous Presettable 4-Bit Binary Counter TC7MH161FK Asynchronous Clear TC7MH163FK Synchronous Clear

The TC7MH161FK and 163FK are advanced high speed CMOS synchronous presettable 4-bit binary counters fabricated with silicon gate C^2MOS technology.

They achieve the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

The CK input is active on the rising edge. Both $\overline{\text{LOAD}}$ and $\overline{\text{CLR}}$ inputs are active on low logic level.

Presetting of each IC's is synchronous to the rising edge of CK. The clear function of the TC7MH163FK is synchronous to CK, while the TC7MH161FK are cleared asynchronously.



Weight: 0.02 g (typ.)

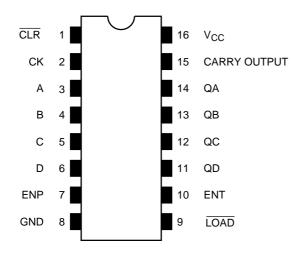
Two enable inputs (ENP and ENT) and CARRY OUTPUT are provided to enable easy cascading of counters, which facilitates easy implementation of n-bit counters without using external gates.

An input protection circuit ensures that 0 to 7 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

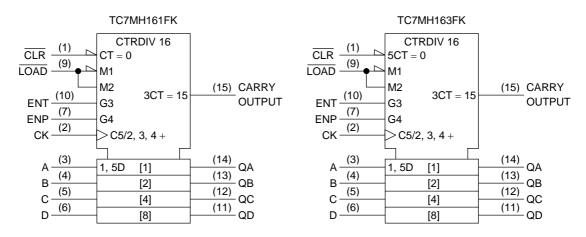
Features

- High speed: $f_{max} = 185 \text{ MHz}$ (typ.) (V_{CC} = 5 V)
- Low power dissipation: $ICC = 4 \mu A (max) (Ta = 25^{\circ}C)$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Power down protection is equipped with all inputs.
- Balanced propagation delays: $t_{pLH}\approx t_{pHL}$
- Wide operating voltage range: $V_{CC (opr)} = 2 \sim 5.5 V$
- Low noise: VOLP = 0.8 V (max)
- Pin and function compatible with 74ALS161/163

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

TC7MH161FK				TC7MH163FK				Outputs									
		Inputs					Inputs			Outputs				Fun			Function
CLR	LD	ENP	ENT	СК	CLR	LD	ENP	ENT	СК	QA	QB	QC	QD				
L	Х	Х	Х	Х	L	Х	Х	Х		L	L	L	L	Reset to "0"			
Н	L	Х	Х		Н	L	Х	Х		А	В	С	D	Reset data。			
н	Н	Х	L		Н	Н	Х	L		No change				No count			
н	Н	L	Х		Н	Н	L	Х		No change				No count			
Н	Н	Н	Н		Н	Н	Н	Н		Count up				Count			
Н	Х	Х	Х		Х	Х	Х	Х			No cł	nange		No count			

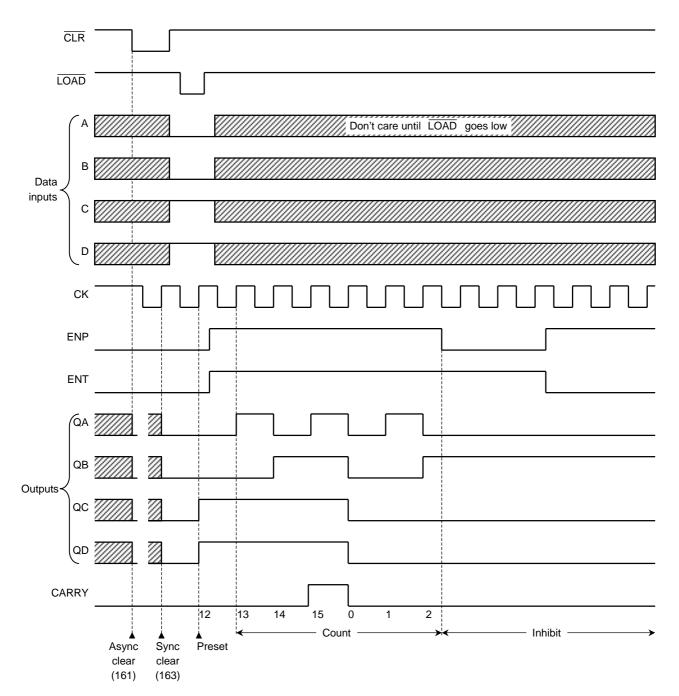
X: Don't care

A, B, C, D: Logic level of data inputs

Carry: $CARRY = ENT \cdot QA \cdot QB \cdot QC \cdot QD$

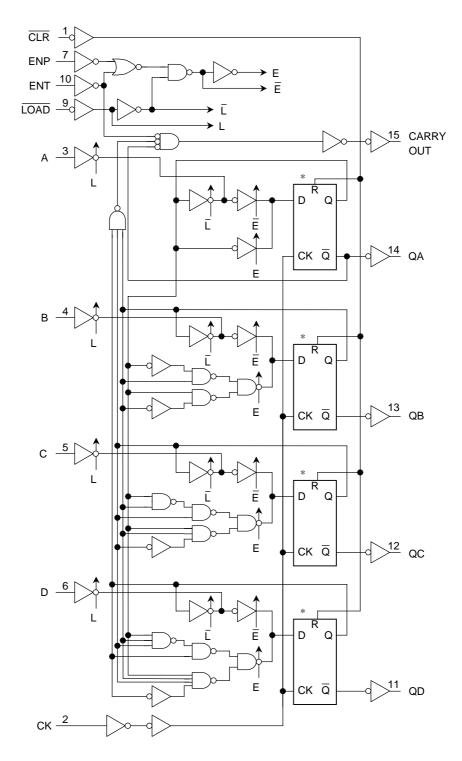
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Timing Chart



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System Diagram



*:Truth table of internal F/F

	TC7	7MH16 ⁻	1FK		TC7MH163FK						
D	СК	R	Q	IQ	D	СК	R	Q	Q		
х	Х	Н	L	н	Х		Н	L	Н		
L		L	L	н	L		L	L	Н		
Н		L	Н	L	Н		L	Н	L		
х	→_	L	No cł	nange	Х	→	Х	No ch	nange		

X: Don't care

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7.0	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	V _{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input diode current	I _{IK}	-20	mA
Output diode current	IOK	±20	mA
DC output current	IOUT	±25	mA
DC V _{CC} /ground current	ICC	±50	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	-65~150	°C

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0~5.5	V
Input voltage	V _{IN}	0~5.5	V
Output voltage	V _{OUT}	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
Input rise and fall time	dt/dv	0~100 (V_{CC} = 3.3 \pm 0.3 V)	ns/V
	u, uv	0~20 (V_{CC} = 5 \pm 0.5 V)	113/ V

Electrical Characteristics

DC Characteristics

Charac	Characteristics Sym		Toot	Condition		Ta = 25°C			Ta = -40~85°C		Unit	
Charac	ciensilos	Symbol			$V_{CC}(V)$	Min	Тур.	Max	Min	Max	Unit	
					2.0	1.50	_	_	1.50			
Input voltage	High level	V _{IH}		_	3.0~5.5	$\begin{array}{c} V_{CC} \\ \times \ 0.7 \end{array}$			$\begin{array}{c} V_{CC} \\ \times \ 0.7 \end{array}$	_	V	
mput voltage					2.0			0.50	_	0.50	v	
	Low level	VIL		_	3.0~5.5			$V_{CC} \times 0.3$	_	Max 		
			V _{IN} = V _{IH} or V _{IL}		2.0	1.9	2.0	_	1.9	_		
	High level	V _{OH}		I _{OH} = -50 μA	3.0 2.9	3.0		2.9				
					4.5	4.4	4.5		4.4			
			12	$I_{OH} = -4 \text{ mA}$	3.0	2.58	_	_	2.48	_		
Output				I _{OH} = -8 mA	4.5	3.94	_	_	3.80	_	V	
voltage					2.0	_	0	0.1	_	0.1	v	
				$I_{OL} = 50 \ \mu A$	3.0		0	0.1		0.1	-	
	Low level	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}		4.5	_	0	0.1	_	0.1		
				I _{OL} = 4 mA	3.0			0.36		0.44		
				I _{OL} = 8 mA								
Input leakage	current	I _{IN}	V _{IN} = 5.5 V	V or GND	0~5.5		_	±0.1		±1.0	μA	
Quiescent sup	ply current	Icc	$V_{IN} = V_{CC}$	or GND	5.5			4.0		40.0	μA	

Timing Requirements (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol Test Co		Condition		Ta = 25°C	Ta = -40~85°C	Unit	
Characteristics	Symbol	Test Condition	UT	V _{CC} (V)	Limit	Limit	Unit	
Minimum pulse width	t _{w (H)}	Figure 1		$\textbf{3.3}\pm\textbf{0.3}$	5.0	5.0	ns	
(CK)	t _w (L)			5.0 ± 0.5	5.0	5.0	115	
Minimum pulse width	t (1)	Figure 4	(Note1)	$\textbf{3.3}\pm\textbf{0.3}$	5.0	5.0	- ns	
(CLR)	t _{w (L)}	rigule 4		5.0 ± 0.5	5.0	5.0		
Minimum set-up time	ts	Figure 2		$\textbf{3.3}\pm\textbf{0.3}$	5.5	6.5	ns	
(A, B, C, D)	۲s	Figure 2		5.0 ± 0.5	4.5	4.5	115	
Minimum set-up time	+	Figure 2		$\textbf{3.3}\pm\textbf{0.3}$	8.0	9.5	ns	
(LOAD)	ts			5.0 ± 0.5	5.0	6.0	115	
Minimum set-up time	+	Figure 3		$\textbf{3.3}\pm\textbf{0.3}$	7.5	9.0	ns	
(ENT, ENP)	ts			5.0 ± 0.5	5.0	6.0	115	
Minimum set-up time	+	Figure 5	(Note2)	$\textbf{3.3}\pm\textbf{0.3}$	4.0	4.0	ns	
(CLR)	ts	rigule 5	(100182)	5.0 ± 0.5	3.5	3.5	115	
Minimum hold time	+.			$\textbf{3.3}\pm\textbf{0.3}$	1.0	1.0		
	t _h	Figure 2, Figure 3		5.0 ± 0.5	1.0	1.0	ns	
Minimum hold time	+ .	Figure F	(Note2)	$\textbf{3.3}\pm\textbf{0.3}$	1.0	1.0	20	
(<u>CLR</u>)	t _h	Figure 5	(Note2)		1.5	1.5	ns	
Minimum removal time	+	Figure 4	(Note1)	$\textbf{3.3}\pm\textbf{0.3}$	2.5	2.5	20	
(CLR)	t _{rem}	Figure 4	(Note1)	5.0 ± 0.5	1.5	1.5	ns	

Note1: for TC7MH161FK only

Note2: for TC7MH163FK only

AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Sumbol	Test Condition			-	Ta = 25°0)	Ta = -4	0~85°C	Unit
Characteristics	Symbol	Test Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	Unit
			3.3 ± 0.3	15		8.3	12.8	1.0	15.0	
Propagation delay time	t _{pLH}	Figure 1, Figure 2	3.3 ± 0.3	50		10.8	16.3	1.0	18.5	20
(CK-Q)	t _{pHL}	Figure 1, Figure 2	50 ± 05	15		4.9	8.1	1.0	9.5	ns
			5.0 ± 0.5	50		6.4	10.1	1.0	11.5	
Dren e netien de leu time			3.3 ± 0.3	15		8.7	13.6	1.0	16.0	
Propagation delay time	t _{pLH}	Figure 1	3.3 ± 0.3	50	_	11.2	17.1	1.0	19.5	20
(CK-CARRY)	t _{pHL}		5.0 ± 0.5	15	_	4.9	8.1	1.0	9.5	ns
[Count mode]			5.0 ± 0.5	50	_	6.4	10.1	1.0	11.5	
			3.3 ± 0.3	15	_	11.0	17.2	1.0	20.0	
Propagation delay time (CK-CARRY)	t _{pLH}	Figure 2	3.3 ± 0.3	50	_	13.5	20.7	1.0	23.5	20
[Preset mode]	t _{pHL}		5.0 ± 0.5	15	_	6.2	10.3	1.0	12.0	ns
[i leset mode]			5.0 ± 0.5	50	_	7.7	12.3	1.0	14.0	
			3.3 ± 0.3	15	_	7.5	12.3	1.0	14.5	ns
Propagation delay time	t _{pLH}	Figure 6		50	_	10.5	15.8	1.0	18.0	
(ENT-CARRY)	t _p HL	Figure 6	5.0 ± 0.5	15	_	4.9	8.1	1.0	9.5	
				50	_	6.4	10.1	1.0	11.5	
			3.3 ± 0.3	15	_	8.9	13.6	1.0	16.0	
Propagation delay time	4	Figure 4 (Note 4)	3.3 ± 0.3	50	_	11.2	17.1	1.0	19.5	20
(<u>CLR</u> -Q)	t _{pHL}	Figure 4 (Note4)		15	_	5.5	9.0	1.0	10.5	ns
			5.0 ± 0.5	50	_	7.0	11.0	1.0	12.5	
			3.3 ± 0.3	15	_	8.4	13.2	1.0	15.5	
Propagation delay time	*	Figure 4 (Note4)	5.5 ± 0.5	50	_	10.9	16.7	1.0	19.0	20
(CLR -CARRY)	t _{pHL}	Figure 4 (Note4)	5.0 ± 0.5	15	_	5.0	8.6	1.0	10.0	ns
			5.0 ± 0.5	50		6.5	10.6	1.0	12.0	
			3.3 ± 0.3	15	80	130		70		
Maximum clock froquency	f		5.5 ± 0.5	50	55	85		50		MHz
Maximum clock frequency	f _{max}		5.0 ± 0.5	15	135	185	_	115	_	IVITZ
			J.U ± 0.5	50	95	125		85		
Input capacitance	C _{IN}		_		_	4	10		10	pF
Power dissipation capacitance	C _{PD}			(Note3)	_	23	_		_	pF

Note3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

When the outputs drive a capacitive load, total current consumption is the sum of C_{PD} , and ΔI_{CC} which is obtained from the following formula:

$$\Delta I_{CC} = f_{CK} \cdot V_{CC} \left(\frac{C_{QA}}{2} + \frac{C_{QB}}{4} + \frac{C_{QC}}{8} + \frac{C_{QD}}{16} + \frac{C_{CO}}{16} \right)$$

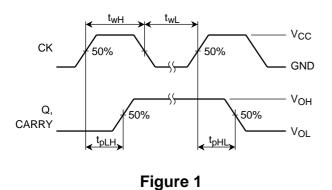
 $C_{QA}\text{-}C_{QD}$ and C_{CO} are the capacitance QA~QD and CARRY OUT, respectively. f_{CK} is the input frequency of the CK.

Note4: for TC7MH161FK only

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AC Test Waveform

Count Mode



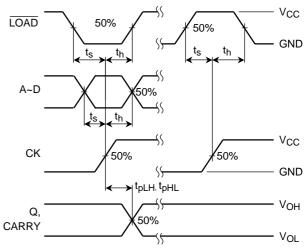


Figure 2

Count Enable Mode

Clear Mode (TC7MH161FK)

Preset Mode

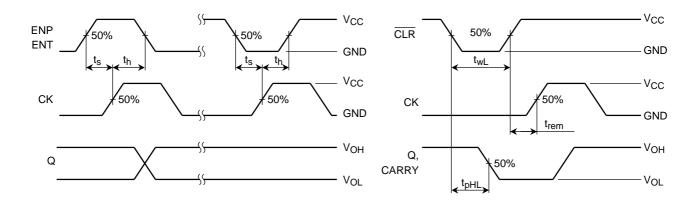


Figure 3



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Clear Mode (TC7MH163FK)

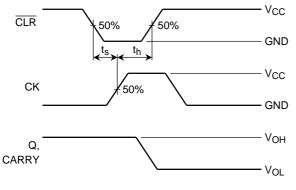
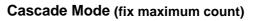


Figure 5



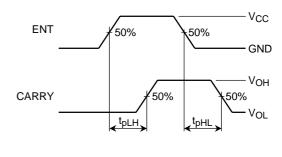
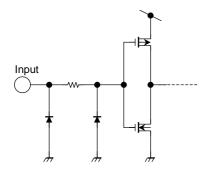


Figure 6

Noise Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

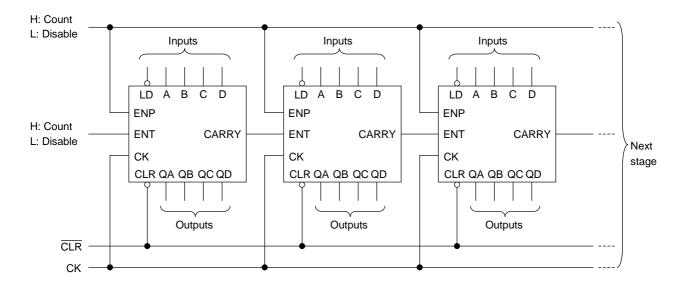
, , , , , , , , , , , , , , , , , , , ,	Symbol	Test Condition		Ta = 25°C		Unit
	Symbol		$V_{CC}(V)$	Тур.	Limit	Offic
Quiet output maximum dynamic V_{OL}	V _{OLP}	C _L = 50 pF	5.0	0.4	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.4	-0.8	V
Minimum high level dynamic input voltage V_{IH}	VIHD	C _L = 50 pF	5.0	_	3.5	V
Maximum low level dynamic input voltage V_{IL}	V _{ILD}	C _L = 50 pF	5.0		1.5	V

Input Equivalent Circuit



Typical Application

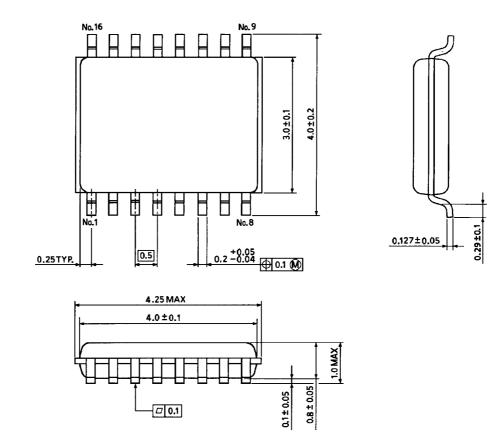
Parallel Carry N-Bit Counter



Package Dimensions

VSSOP16-P-0030-0.50

Unit : mm



Weight: 0.02 g (typ.)

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Handbook" etc..

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